


Form PTO-1449 (MODIFIED)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. 040301/0578		SERIAL NO. Unassigned		
INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>				APPLICANT <div style="text-align: right; font-size: 1.5em; margin-right: 10px;">#3</div> Nobutoshi AOKI et al.				
				FILING DATE November 16, 1999		GROUP ART UNIT Unassigned		
U.S. PATENT DOCUMENTS								
EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE IF APPROPRIATE	
J	A1	5,356,821	10/1994	Naruse et al.	437	34		
							JC542 U.S. PTO 09/440928  11/16/99	
FOREIGN PATENT DOCUMENTS								
	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION	
							YES	NO
J	A2	2876866	01/1999	Japan				Abstract
	A3	4-25176	01/1992	Japan				Abstract
OTHER DOCUMENTS <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>								
J	A4	Tsu-Jae King et al., IEEE ELECTRON DEVICE LETTERS vol 12, no. 10, "A Variable-Work-Function Polycrystalline-Si _{1-x} Ge _x Gate Material for Submicrometer CMOS Technologies, pp. 533-535, (10/10/91)						
EXAMINER				DATE CONSIDERED				
				9/21/2001				
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